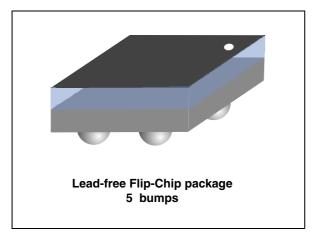
BAL-CW1250D3



$50~\Omega$ nominal input / conjugate match balun to CW1250/CW1260/CW1150/CW1160, with integrated harmonic filter



Datasheet - production data

Features

- 50 Ω nominal input / match ST-Ericsson RF IC CW1250, CW1150, CW1260, CW1160
- Low insertion loss
- · Low amplitude imbalance
- Low phase imbalance
- DC blocking access on single RF input
- Small footprint: < 1.2 mm²

Benefits

- Extremely low profile (< 550 µm after reflow)
- Integrate matching network
- High RF performance
- RF components count and area reduction

Applications

 Balun with integrated matching for ST-Ericsson RF IC CW1250, C1150, CW1260

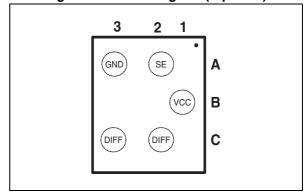
Description

STMicroelectronics BAL-CW1250D3 is a balun (balanced/unbalanced device) designed to transform a single ended signal to differential signals in WLAN application.

This BAL-CW1250D3, with low insertion losses in the bandwidth 2400 MHz to 2500 MHz, has been customized for CW1250, CW1150, CW1260, CW1160 transceiver. The differential output embeds an integrated matching network adapted to the transceiver.

The BAL-CW1250D3 has been designed using STMicroelectronics IPD (integrated passive device) technology on non-conductive glass substrate to optimize RF performance.

Figure 1. Pinout diagram (top view)



Characteristics BAL-CW1250D3

1 Characteristics

Table 1. Absolute maximum ratings (limiting values)

Symbol	Parameter	Value			Unit
	Falametei		Тур	Max	Oilit
P _{IN}	Average power RF _{IN}			24	dBm
	ESD ratings MIL STD883C (HBM: C = 100 pF, R = 1.5 k Ω , air discharge)	2000			
V _{ESD}	ESD ratings charged device model (JESD22-C101-D)	500			V
	ESD ratings machine model (MM: C = 200 pF, R = 25 Ω , L = 500 nH)	200			
T _{OP}	Operating temperature	-30 to +85		°C	

Table 2. Impedances ($T_{amb} = 25 \, ^{\circ}C$)

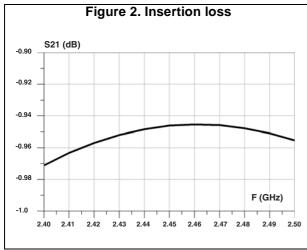
Symbol	Symbol Parameter		Value			
Symbol			Тур	Max	Unit	
Z _{OUT}	Nominal differential output impedance		matched		Ω	
Z _{IN}	Nominal input impedance		50		Ω	

Table 3. RF performance ($T_{amb} = 25 \, ^{\circ}C$)

Symbol	Parameter		Unit		
	Farameter		Тур	Max	Onit
F	Frequency range (bandwidth)	2400		2500	MHz
IL	Insertion loss in bandwidth		0.97		dB
RL _{SE}	Single ended return loss in bandwidth		-21		dB
RL _{DIFF}	Differential return loss in bandwidth		-24		dB
фimb	Phase imbalance	-10		10	0
Aimb	Amplitude imbalance	-1	0.1	1	dB
Att _{2f0}	2nd harmonic attenuation		-19		dB

BAL-CW1250D3 Characteristics

1.1 Measurements



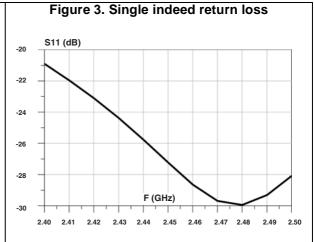
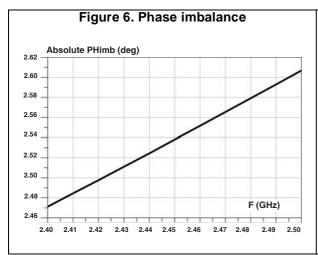


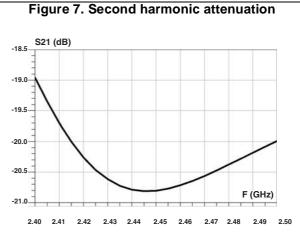
Figure 5. Amplitude imbalance

Absolute Aimb (dB)

-0.36
-0.35
-0.34
-0.33
-0.32
-0.31
-0.30
-0.29

2.40 2.41 2.42 2.43 2.44 2.45 2.46 2.47 2.48 2.49 2.50





Package information BAL-CW1250D3

2 Package information

- Epoxy meets UL94, V0
- Lead-free package

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK[®] is an ST trademark.

2.1 Flip-Chip package information

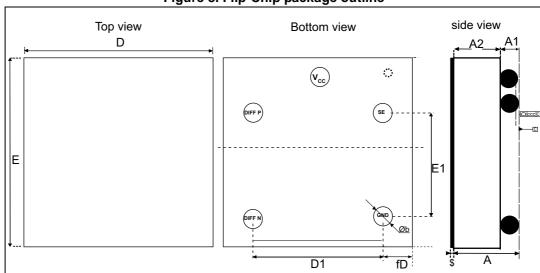


Figure 8. Flip-Chip package outline

Table 4. Flip-Chip package mechanical data

Parameter	Description	Min.	Тур.	Max.	Unit
Α	Bump height + substrate thickness	0.570	0.630	0.690	mm
A1	Bump height	0.155	0.205	0.255	mm
A2	Substrate thickness		0.400		mm
b	Bump diameter	0.215	0.255	0.295	mm
D	Y dimension of the die	1.150	1.200	1.250	mm
D1	Y pitch		0.760		mm
Е	X dimension of the die	0.940	0.990	1.040	mm
E1	X pitch		0.400		mm
fD	Distance from bump to edge of die on Y axis		0.105		mm
ccc				0.05	mm
\$			0.025	·	mm

BAL-CW1250D3 Package information

Figure 9. Footprint

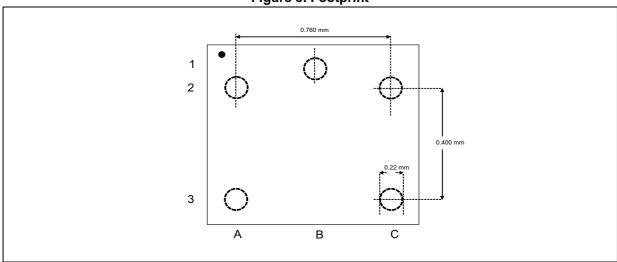
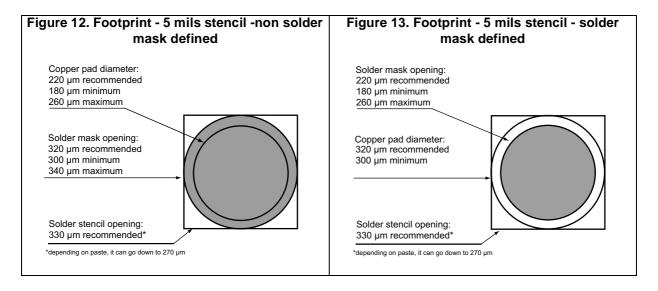
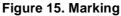


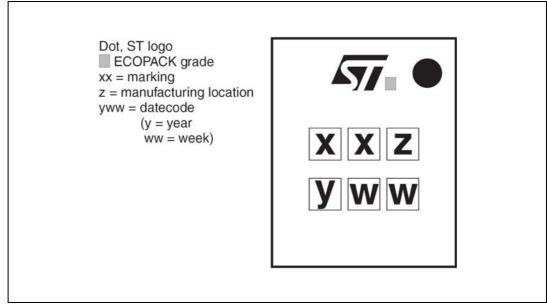
Figure 10. Footprint - 3 mils stencil -non solder Figure 11. Footprint - 3 mils stencil - solder mask defined mask defined Copper pad diameter: Solder mask opening: 220 µm recommended 220 µm recommended 180 µm minimum $180~\mu m$ minimum 260 µm maximum $260~\mu m$ maximum Copper pad diameter: 320 µm recommended Solder mask opening: 320 µm recommended 300 µm minimum 300 µm minimum 340 µm maximum Solder stencil opening: Solder stencil opening: 220 µm recommended $220~\mu m$ recommended



Package information BAL-CW1250D3

Figure 14. Recommended land pattern (used for balun characterization)





BAL-CW1250D3 Package information

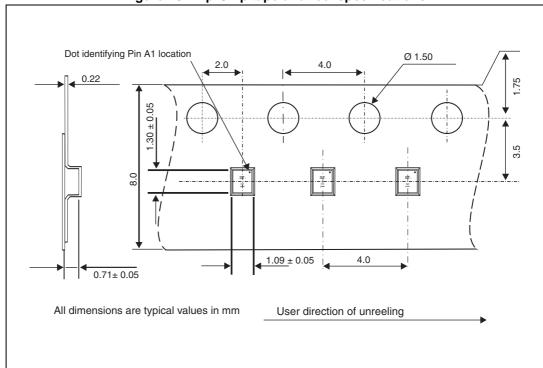


Figure 16. Flip-Chip tape and reel specifications

Note: More information is available in the STMicroelectronics Application note:

AN2348 Flip-Chip: "Package description and recommendations for use"

Application information 3

2.4G/5G RF transceiver BAL-CW1250D3 2.4GHz FEM BPF 2.4GHz DIP2450-01D3 Rx/Tx BPF50-01D3 5GHz FEM

Figure 17. Application schematic

Note:

More information is available in the application notes:

AN2348 Flip-Chip package description and recommendations for use

4 Ordering information

Table 5. Ordering information

Part Number	Marking	Package	Weight	Base Qty	Delivery Mode
BAL-CW1250D3	SG	Flip-Chip	1.46 mg	5000	Tape and reel(7")

5 Revision history

Table 6. Document revision history

Date	Revision	Changes
23-May-2013	1	Initial release.
23-Sep-2015	2	Updated Figure 8. Added Figure 10, Figure 11, Figure 12, Figure 13 and Table 4. Reformatted to current standards.

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